750	-	830	nm

	8	3	0	-	9	2	0	r	n	n	
	92	20).	_	1 .	10)()	nı	m	
1	1	0	0	-	1	3	0	0	n	n	า
1	3	0	0	_	1	4	5	0	n	n	า
1	4	.5	0	-	1	6	5	0	n	n	า
1	6	5	0	-	1	8	5	0	n	n	า
1	8	5	0	_	1	9	0	0	n	n	า
1	9	0	0	_	2	22	20	0	r	۱r	r
2	22	0	0	-	2	6	0	0	n	n	า
2	26	0	0	_	2	9	0	0	n	n	า

DFB laser diodes from 1900 nm to 2200 nm

nanoplus single mode laser diodes

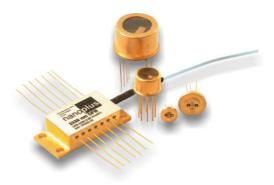
nanoplus is the only manufacturer worldwide routinely providing single mode laser diodes at any wavelength from 750 nm to 2900 nm. Our patented distributed feedback laser diodes deliver single mode emission with well defined optical properties enabling a wide range of applications. At wavelengths from 7 to 12 µm, nanoplus manufactures quantum cascade lasers.

nanoplus lasers operate reliably in more than 5000 installations worldwide, including chemical and metallurgical industries, gas pipelines, power plants, medical systems, airborne and satellite applications.

key features

- very high spectral purity
- ✓ narrow linewidth typically < 3 MHz
- excellent reliability
- wide variety of packaging options
- customer-specific designs available





application areas

- high performance gas sensing for process and environmental control
- precision metrology
- ✓ atomic clocks
- ✓ spectroscopy
- ✓ space technology

nanoplus lasers with excellent performance are specifically designed and characterized to fit your needs. This data sheet summarizes typical properties of nanoplus DFB lasers in the 1900 nm to 2200 nm range. This wavelength range permits, e.g. trace gas sensing of CO₂, N₂O, H_2CO , HBr, with excellent sensitivity. Overleaf data for lasers used for high performance CO_2 sensing are given as an example.

general ratings (T = 25 °C)	symbol	unit	typical	
optical output power	P _{out}	mW	3	On request, lasers
reverse Voltage	Vr	V	1.8	with specifically optimized proper-
forward Current	l _f	mA	100	ties, e.g. higher
side mode suppression ratio (SMSR)		dB	> 32	output power, are available.
laser packaging options	For dimensions and accessories,			
TO5.6 header with or without cap				

TO9 header with or without cap

TO5 with TEC and NTC

butterfly housing with FC/APC fibre

or dimensions and accessories, please see www.nanoplus.com

Further packaging options available on request.

device protected by US patent 6.671.306 US patent 6.846.689 EU patent EP0984535

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DFB2004.02

Rev.

nanoplus

Fig. 1

Room

2004 nm

Fig. 2

ratures

nanoplus DFB laser diodes at 2004 nm

A wide variety of gas molecules, defects in solids etc. exhibit characteristic absorption lines in the near infrared. At 2004 nm for example, there is a strong absorption line of CO₂, which can be used for laser based sensing with very high sensitivity. This data sheet reports performance data of nanoplus DFB lasers at this wavelength. Similar performance data are obtained in the entire wavelength range from 1900 nm to 2200 nm. For examples of performance data of nanoplus lasers in other wavelength ranges, please see www.nanoplus.com or contact sales@nanoplus.com.

0 intensity (dB) -20 -40 temperature cw spectrum of a nanoplus DFB laser diode operating at -60 2004 2000 2008 wavelength (nm) 30°C 25°C 20°C In many applications, temperature and/or current variations are used to adjust the 2005 laser emission precisely to the vavelength (nm) target wavelength. 2004 2003 Mode hop free tuning of 2004 nm based DFBs by current variation at different tempe-2002 70 80 90 50 60 100 110

electrooptical characteristics (T = 25 °C) symbol unit min typ max peak wavelength λ nm 2003 2004 2005 threshold current mΑ 20 25 50 I_{th} slope efficiency mW / mA 0.10 0.20 0.23 e temperature tuning coefficient C_T nm/K 0.18 0.20 0.22 current tuning coefficient C nm/mA 0.01 0.02 0.03 slow axis (FWHM) degrees 17 20 25 fast axis (FWHM) 45 degrees 35 40 WхH emitting area 4.5 x 1.5 5 x 2 μm x μm 3 x 1 °C storage temperatures Ts - 40 + 20 + 80 + 50 operational temperature at case Τc °C - 20 + 25



nanoplus Nanosystems and Technologies GmbH Oberer Kirschberg 4 D-97218 Gerbrunn

CLASS 3B LASER PRODUC

WARNING! SD - SENSITIVE DEVIC

NGF

ASER RADIATION AVOID

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current (mA)

